High Voltage Ceramic Capacitors For Surface Mounting 1 to 5 kVDC





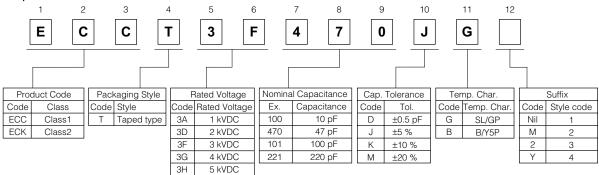
■ Features

- Resin molded SMD type for reflow solderings
- High reliability through use of disc capacitor element
- Wide rated voltage ranges from 1 kV to 5 kV, through a disc element which withstand high voltage and outcurve terminals
- Wide rated voltage range 1 to 5 kV

■ Recommended Application

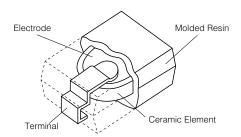
- Ballast circuit of LCD backlighting inverter (For 3 to 5 kVDC Char.SL/GP)
- Snubber circuit of switching power supply (For 1 to 2 kVDC Char.B/Y5P)

■ Explanation of Part Numbers



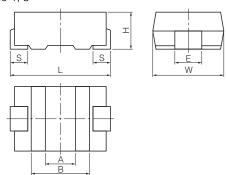
■ Construction

Inside Terminal

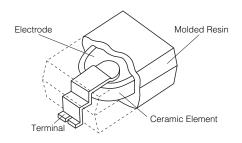


■ Dimensions in mm (not to scale)

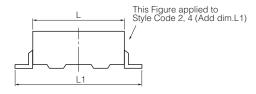
• style 1, 3



Outside Terminal



• style 2, 4



	Symbol	L1	L	W	Ι	S	Е	Α	В
	Style 1	_	7.1±0.5	6.3±0.3	2.5±0.3	1.45±0.30	2.5±0.2	(2.0)	(3.7)
Dim	Style 2	10.8±0.5	6.8±0.5	6.3±0.3	2.5±0.3	1	2.5±0.2	(2.0)	(3.7)
(mm)	Style 3	_	5.7±0.5	4.5±0.3	2.3max.	0.85±0.30	2.5±0.2	(1.7)	(3.1)
	Style 4	9.4±0.3	5.5±0.5	4.5±0.3	2.3±0.2	1	2.5±0.2	(1.7)	(3.1)

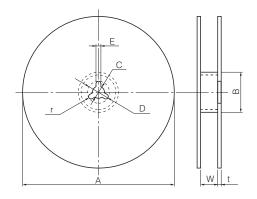
■ Specifications

Characteristics		Char. SL/GP		Char. B/Y5P
Operating Temperature Range			-25 to	105 °C
Rated Voltage	2 to 3 kVDC	4 to 5 kVDC	5 kVDC	1 to 2 kVDC
Dielectric				200 % of Rated Voltage
Withstanding Voltage	for 1 to 5 seconds	for 1 to 5 seconds	for 1 to 5 seconds	for 1 to 5 seconds
Capacitance	Within the speci at 1 MHz±20 %			Within the specified tolerance, when measured at 1 kHz±20 %, 1 to 5 Vrms. and 20 °C
\mathbb{Q} or Dissipation Factor ($ an \delta$)	30 pF or under over 30 pF at 1 MHz±20 %	Q ≥ 1000	,	tan δ ≤ 0.025 at 1 kHz±20 %,1 to 5 Vrms. and 20 °C
Insulation Resistance	10000 M Ω min	. at 500 VDC an	d 1 minute elect	rification
Temperature Characteristics		1000 ppm/ °C		Max. Cap. Change:±10 % (Temperature Range: -25 to 85 °C)
	Temperat (Temperat	ure Range : 20 t	to 85 °C)	

Packaging Methods (Taping)Minimum Quantity/Packing Unit

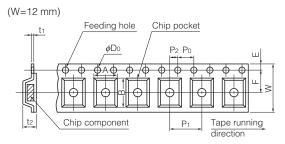
Туре	Packaging Style	Part Number		Minimum Packing Quantity	Packing Quantity in Carton	Carton Dimensions in mm LxWxH
1 to 5 kVDC (style 1)	Embossed Carrier Taping	ECUT3UUUUU	5 to 470 pF	2000 pcs./reel	6000 pcs.	350×350×62
5 kVDC (style 2)	Embossed Carrier Taping	ECCT3H	5 to 27 pF	2000 pcs./reel	4000 pcs.	350×350×62
4 kVDC (style 3)	Embossed Carrier Taping	ECCT3G□□□JG2	10 to 27 pF	3000 pcs./reel	9000 pcs.	350×350×62
5 kVDC (style 4)	Embossed Carrier Taping	ECCT3H	5 to 15 pF	3000 pcs./reel	6000 pcs.	350×350×62

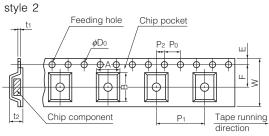
Reel



Embossed Carrier Taping

style 1, 3, 4





						U	nit:(mm)
Symbol	Ι Λ	B	ח	F	۱۸/	+	r	-

- 5	Symbol	Α	В	С	D	Е	W	t	r
D:	style 1, 3						13.5±1.5		
Dim. (mm)	style 2	330±5	60 min.	13.0±0.5	21.0±1.0	2.0±0.5	25.5±1.5	2.0±0.5	R1.0
(111111)	style 4						17.5±1.5		

											Uni	t:(mm)
Syr	mbol	Α	В	W	F	Е	P ₁	P ₂	Po	φDo	t1	t2
	style1	6.5 ±0.2	7.5 ±0.2	12.0 ±0.3	5.5 ±0.1	1.75 ±0.10	8.0 ±0.1	2.0 ±0.1	4.0 ±0.1	1.5 +0.1 -0	0.3 ±0.1	3.2 ±0.3
Dim.	style2	6.65 ±0.20	11.2 ±0.2	24.0 ±0.3	11.5 ±0.1	1.75 ±0.10	12.0 ±0.1	2.0 ±0.1	4.0 ±0.1	1.5 +0.1 -0	0.3 ±0.1	3.2 ±0.3
(mm)	style3	4.8 ±0.2	6.0 ±0.2	12.0 ±0.3	5.5 ±0.1	1.75 ±0.10	8.0 ±0.1	2.0 ±0.1	4.0 ±0.1	1.5 +0.1 -0	0.3 ±0.1	2.8 ±0.3
	style4	4.7 ±0.2	10.0 ±0.5	16.0 ±0.3	7.5 ±0.1	1.75 ±0.10		2.0 ±0.1	4.0 ±0.1	1.5 +0.1 -0	0.3 ±0.1	2.85 ±0.30

Panasonic

Leader Part and Taped End

Not loaded 40 mm min.	Chip component position	Not loaded 20 mm min.	Leader tape 400 mm min.
00000000	000000000000000000000000000000000000000	0000000000	

Tape running direction

■ Ratings and Characteristics

Rated Voltage 1 to 5 kVDC

Rated Voltage	Part Number	Capacitance (pF)	Cap. Tolerance (%)	Temp. Char	Style		
	ECCT3H050DGM	5	±0.5 pF	SL/GP			
	ECCT3H100JGM	10	±5	SL/GP			
	ECCT3H120JGM	12	±5	SL/GP			
	ECCT3H150JGM	15	±5	SL/GP	Style 2		
	ECCT3H180JGM	18	±5	SL/GP			
5 kVDC	ECCT3H220JGM	22	±5	SL/GP			
JKVDC	ECCT3H270JGM	27	±5	SL/GP			
	ECCT3H050DGY	5	±0.5 pF	SL/GP			
	ECCT3H080DGY	8	±0.5 pF	SL/GP			
	ECCT3H100JGY	10	±5	SL/GP	Style 4		
	ECCT3H120JGY	12	±5	SL/GP			
	ECCT3H150JGY	15	±5	SL/GP			
	ECCT3G100DG2	10	±0.5 pF	SL/GP			
İ	ECCT3G120JG2	12	±5	SL/GP			
	ECCT3G150JG2	15	±5	SL/GP	Ctulo 2		
	ECCT3G180JG2	18	±5	SL/GP	Style 3		
4 kVDC	ECCT3G220JG2	22	±5	SL/GP			
	ECCT3G270JG2	27	±5	SL/GP			
Ī	ECCT3G330JG	33	±5	SL/GP			
Ī	ECCT3G390JG	39	±5	SL/GP	Style 1		
	ECCT3G470JG	47	±5	SL/GP			
	ECCT3F100DG2	10	±0.5 pF	SL/GP			
	ECCT3F120JG2	12	±5	SL/GP			
Ī	ECCT3F150JG2	15	±5	SL/GP	Style 3		
	ECCT3F180JG2	18	±5	SL/GP			
017/00	ECCT3F220JG2	22	±5	SL/GP	,		
3 kVDC	ECCT3F270JG2	27	±5	SL/GP			
Ī	ECCT3F330JG2	33	±5	SL/GP			
	ECCT3F390JG	39	±5	SL/GP			
ļ	ECCT3F470JG	47	±5	SL/GP			
	ECCT3F560JG	56	±5	SL/GP			
	ECCT3D680JG	68	±5	SL/GP			
	ECKT3D101KB	100	±10	B/Y5P			
İ	ECKT3D121KB	120	±10	B/Y5P			
014/00	ECKT3D151KB	150	±10	B/Y5P	Style 1		
2 kVDC	ECKT3D181KB	180	±10	B/Y5P	•		
İ	ECKT3D221KB	220	±10	B/Y5P			
İ	ECKT3D271KB	270	±10	B/Y5P			
İ	ECKT3D331KB	330	±10	B/Y5P			
411/150	ECKT3A391KB	390	±10	B/Y5P			
1 kVDC	ECKT3A471KB	470	±10	B/Y5P			

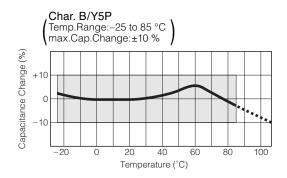
Design and specifications are each subject to change without notice. Ask factory for the current technical specifications before purchase and/or use. Should a safety concern arise regarding this product, please be sure to contact us immediately.

Notes * This part number indicates taped type.

* Capacitance 9 pF or under is available by special order.

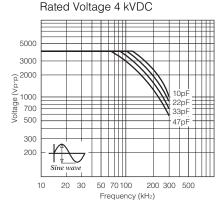
- Typical Characteristics
- Temperature Characteristics
 Char. SL/GP

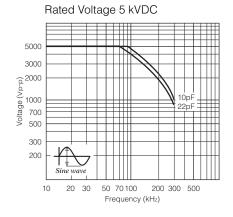
(Temp.Coeff.:+350 to -1000 ppm/°C) Capacitance Change (%) +5 -5 -10 -15 -20 Temperature (°C)



Characteristics of Voltage-Frequency Rated Voltage 3 kVDC

47pF





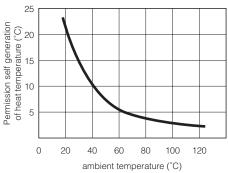
The graphs above show the maximum permissable voltage when using a capacitor with an AC sine wave voltage.

When measuring this voltage in room temperature (25 $^{\circ}$ C), the capacitor self-heat generation will rise a maximum of 20 $^{\circ}$ C. When using a pulse voltage or an AC voltage other than a sine wave, confirm that the capacitor self-heat generation is less

The self-heat generation temperature is the difference between the surface temperature and the ambient room temperature. As for the situation when the self-heat generation temperature is more than 25 °C, refer to the figure on the right.

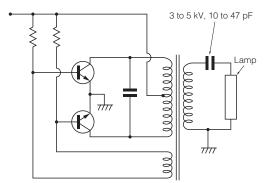
than 20 °C in an ambient room temperature of 25 °C.

Permission self generation of heat temperature vs. ambient temperature



Application Examples

LCD Backlighting Inverter



Primary circuit and Snubber circuit of Switching Power Supply

